

PCS3P7101A

rev 0.1

Low Power Peak EMI Reducing clock synthesizer

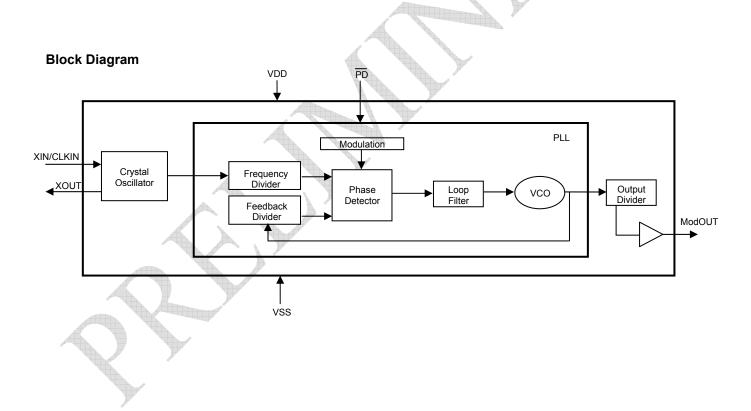
Features

- Generates a 4x low EMI clock at the output
- Input frequency: 25 MHz
- Integrated loop filter components.
- Frequency deviation: ±0.25% (Typ) center spread
- Operates with a 3.3V Supply.
- Low power CMOS design.
- Available in 8-pin SOIC package.
- Pin compatible with ICS 341-22

Product Description

The PCS3P7101A is a low cost, single-output, clock synthesizer. The PCS3P7101A generates a 4x output clock from a 25 MHz standard fundamental mode, inexpensive crystal, or clock. It can replace multiple crystals and oscillators, saving valuable board space and cost. The device employs Spread Spectrum technique to reduce system electro-magnetic interference (EMI).

The device also has a power-down feature that tri-state the clock output and turns off the PLL when the $\overline{\text{PD}}$ pin is taken low.

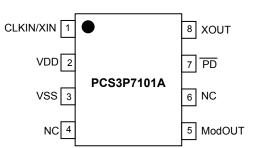


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Pin Description

Pin Name CLKIN/XIN	Туре	Description			
CLKIN/XIN		Description			
	I	Crystal connection or external reference frequency input. This pin has dual functions. It can be connected either to an external crystal or to an external reference clock.			
VDD	Р	Power supply for the entire chip.			
VSS	Р	Ground connection			
NC	-	No Connection			
ModOUT	0	Spread spectrum low EMI 4x clock output.			
NC	-	No Connection			
PD	I	Powers down entire chip. Tri-states CLK outputs when low. Has an Internal pull-up resistor.			
XOUT	0	Crystal connection. If using an external reference, this pin must be left unconnected			
	VSS NC ModOUT NC PD	VSS P NC - ModOUT O NC - PD I			

Absolute Maximum Ratings

Symbol	Parameter	Rating	Unit
$V_{\text{DD}}, V_{\text{IN}}$	Voltage on any pin with respect to Ground	-0.5 to +4.6	V
T _{STG}	Storage temperature	-65 to +125	°C
T _A	Operating temperature	0 to +70	°C
Ts	Max. Soldering Temperature (10 sec)	260	°C
TJ	Junction Temperature	150	°C
T _{DV}	Static Discharge Voltage	2	КV
DV	(As per JEDEC STD 22- A114-B)		

Recommended Operating Conditions¹

Parameter			Min	Тур	Max	Unit
Supply voltage, V _{DD}			3.15	3.3	3.45	V
Low-level input voltage, V_{IL}	V _{DD} = 3.15V to3.45V		-	-	0.8	V
High-level input voltage, V_{IH}	V _{DD} = 3.15V to3.45V		2	-	-	V
High-level output current, I _{OH}	V _{DD} = 3.15V to3.45V		-	-	12	mA
Low-level output current, I _{OL}	V _{DD} = 3.15V to3.45V		-	-	12	mA
Operating free-air temperature, T _A			0	-	70	°C
Note:1 Unused inputs must be held high or low to prevent them from floating.						



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DC Electrical Characteristics

Symbol	Paramo	eter	Min	Тур	Мах	Unit
VIL	Input low voltage		VSS - 0.3	-	0.8	V
VIH	Input high voltage		2.0	-	VDD + 0.5	V
IIL	Input low current		-	-	-35	μA
I _{IH}	Input high current		-	-	35	μA
V _{OL}	Output low voltage (VDD = 3	.3 V, I _{OL} = 12 mA)	-	-	0.4	V
V _{OH}	Output high voltage (VDD = 3	3.3 V, I _{OH} = 12 mA)	2.4	-	-	V
I _{DD}	Static supply current*		-	50		uA
I _{CC}	Dynamic supply current (3.3)	-	TBD	-		
VDD	Operating voltage		3.15	3.3	3.45	V
Z _{OUT}	Output impedance		-	20	-	Ω
CIN	Input Capacitance		-	4	-	pF
Rpd	Internal pull-up resistor	PD		250	-	KΩ
RPUP		CLK output	-	525	-	kΩ

AC Electrical Characteristics for 3.3V Supply

Symbol	Parameter	Min	Тур	Мах	Unit
CLKIN/XIN	Input frequency	-	25	-	MHz
ModOUT	Output frequency	-	100	-	MHz
t _{LH} *	Output rise time (measured from 0.8 to 2.0V)	-	1	-	nS
t _{HL} *	Output fall time (measured at 2.0V to 0.8V)	-	1	-	nS
t _{PU} Power-up time(PLL lock time from power-up)		-	4	10	mS
t _{ON}	Power-up time (first locked cycle after power-up)**	-	4	7	mS
	Synthesis Error(Output Frequency)	-	0	-	ppm
t _{JC}	Jitter (cycle to cycle)	-	TBD	-	pS
t _{JP}	Period Jitter	-	TBD	-	pS
t _D	Output duty cycle	40	50	60	%
t _{ja}	Maximum Absolute Jitter	-	TBD	-	pS

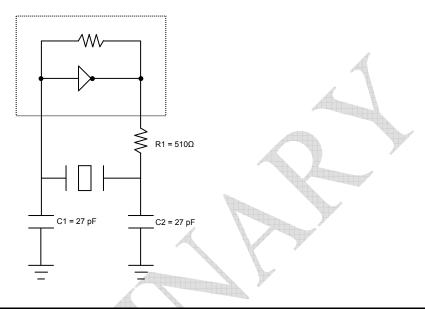
*t_{LH} and t_{HL} are measured into a capacitive load of 15pF ** V_{DD} and XIN/CLKIN input are stable, PD pin is made high from low.



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Typical Crystal Oscillator Circuit



Typical Crystal Specifications

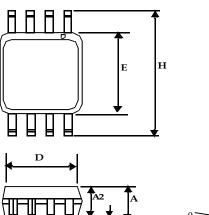
Fundamental AT cut parallel resonant crystal					
Nominal frequency	25MHz				
Frequency tolerance	± 50 ppm or better at 25°C				
Operating temperature range	-25°C to +85°C				
Storage temperature	-40°C to +85°C				
Load capacitance	18pF				
Shunt capacitance	7pF maximum				
ESR	25Ω				

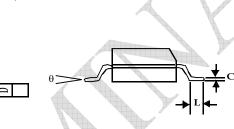


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Package Information







		Dimensions				
	Symbol	Inc	hes	Millimeters		
		Min	Max	Min	Мах	
ð	A1	0.004	0.010	0.10	0.25	
	A	0.053	0.069	1.35	1.75	
S.	A2	0.049	0.059	1.25	1.50	
	В	0.012	0.020	0.31	0.51	
	С	0.007	0.010	0.18	0.25	
	D	0.193	BSC	4.90 BSC		
and a	E	0.154	BSC	3.91 BSC		
	e 0.050 BSC		1.27 BSC			
	Н	0.236 BSC		6.00	BSC	
	L	0.016	0.050	0.41	1.27	
	θ	0°	8°	0°	8°	



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Ordering Information

Part Number	Marking	Package Type	Temperature
PCS3P7101AG-08SR	3P7101AG	8-Pin SOIC, TAPE & REEL, Green	Commercial
PCS3P7101AG-08ST	3P7101AG	8-Pin SOIC, TUBE, Green	Commercial
Device Ordering Informa	tion	A	4
P C S 3 P 7 1 0	1 A G - 0 8	S R y y y R = Tape & Reel, T = Tube or T O = SOT S = SOIC T = TSSOP A = SSOP V = TVSOP B = BGA Q = QFN DEVICE PIN COUNT G = GREEN PACKAGE, LEAD	U = MSOP E = TQFP L = LQFP U = MSOP P = PDIP D = QSOP X = SC-70
		PART NUMBER	
		2 = Non PLL based73 = EMI Reduction84 = DDR support products9	
		PulseCore Semiconductor N	lixed Signal Product

Licensed under US patent Nos 5,488,627 and 5,631,920.

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Note: This product utilizes US Patent # 6,646,463 Impedance Emulator Patent issued to PulseCore Semiconductor, dated 11-11-2003

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